14-stage binary ripple counter with oscillator

Rev. 1 — 2 August 2012

**Product data sheet** 

### 1. General description

The 74HC4060-Q100; 74HCT4060-Q100 are high-speed Si-gate CMOS devices that comply with JEDEC standard no. 7A. They are pin compatible with Low-power Schottky TTL (LSTTL).

The 74HC4060-Q100; 74HCT4060-Q100 are 14-stage ripple-carry counter/dividers and oscillators with three oscillator terminals (RS, RTC and CTC), ten buffered outputs (Q3 to Q9 and Q11 to Q13) and an overriding asynchronous master reset (MR). The oscillator configuration allows design of either RC or crystal oscillator circuits. The oscillator may be replaced by an external clock signal at input RS. In this case keep the other oscillator pins (RTC and CTC) floating. The counter advances on the negative-going transition of RS. A HIGH level on MR resets the counter (Q3 to Q9 and Q11 to Q13 = LOW), independent of other input conditions. In the HCT version, the MR input is TTL compatible, but the RS input has CMOS input switching levels and can be driven by a TTL output by using a pull-up resistor to  $V_{CC}$ .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- All active components on chip
- RC or crystal oscillator configuration
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options

### 3. Applications

- Control counters
- Timers
- Frequency dividers
- Time-delay circuits

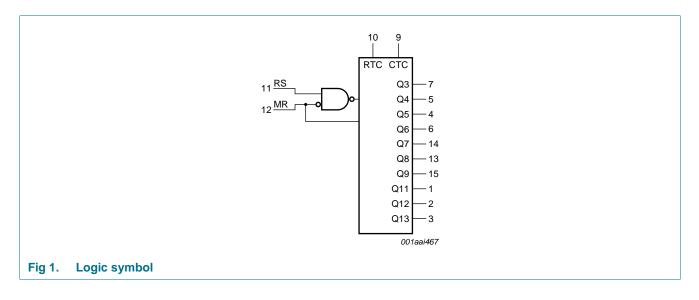


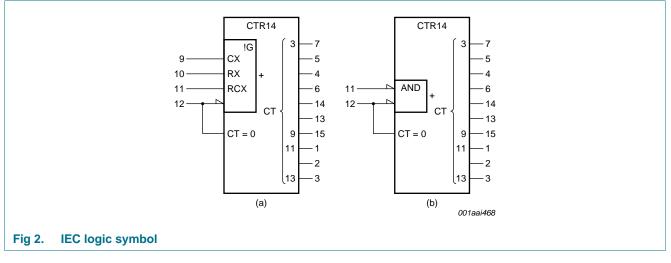
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## 4. Ordering information

Table 1. Ordering i	nformation			
Type number	Package			
	Temperature range	Name	Description	Version
74HC4060D-Q100	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1
74HCT4060D-Q100			body width 3.9 mm	
74HC4060PW-Q100	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74HC4060BQ-Q100	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal-enhanced	SOT763-1
74HCT4060BQ-Q100	–40 °C to +125 °C		very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm	

## 5. Functional diagram



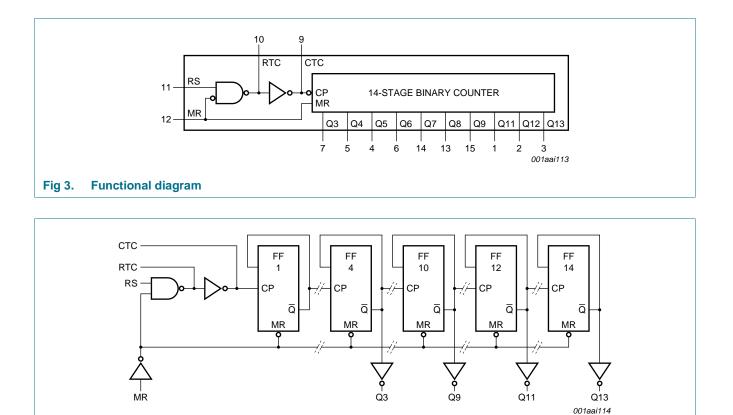


74HC\_HCT4060\_Q100

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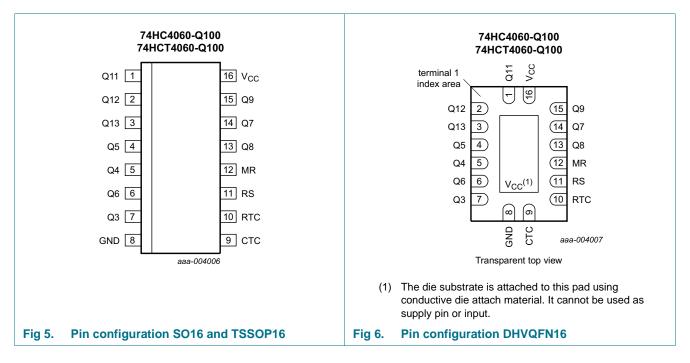


#### Fig 4. Logic diagram

14-stage binary ripple counter with oscillator

## 6. Pinning information

### 6.1 Pinning

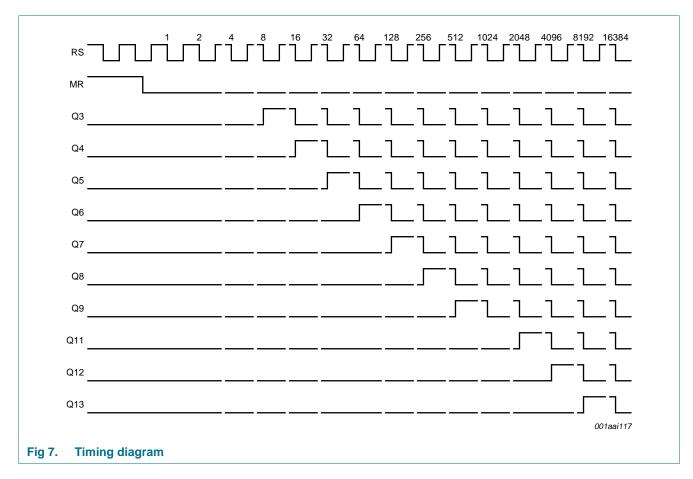


### 6.2 Pin description

Table 2. Pin de	escription	
Symbol	Pin	Description
Q11 to Q13	1, 2, 3	counter output
Q3 to Q9	7, 5, 4, 6, 14, 13, 15	counter output
GND	8	ground (0 V)
СТС	9	external capacitor connection
RTC	10	external resistor connection
RS	11	clock input /oscillator pin
MR	12	master reset input (active HIGH)
V <sub>CC</sub>	16	supply voltage

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### 7. Functional description



### 8. Limiting values

#### Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC}$ + 0.5 V	<u>[1]</u> _	±20	mA
I <sub>OK</sub>	output clamping current	$V_{O}$ < –0.5 V or $V_{O}$ > $V_{CC}$ + 0.5 V	<u>[1]</u> _	±20	mA
lo	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C

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#### Table 3. Limiting values ... continued

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Parameter	Conditions	Min	Max	Unit
total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to +125 \ ^{\circ}C$			
	SO16 package	[2] _	500	mW
	TSSOP16 package	[3] _	500	mW
	DHVQFN16 package	[4] _	500	mW
		total power dissipation $\frac{T_{amb} = -40 \text{ °C to } +125 \text{ °C}}{SO16 \text{ package}}$ TSSOP16 package	total power dissipation $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ $SO16 \text{ package} \qquad \boxed{2} \text{ -}$ $TSSOP16 \text{ package} \qquad \boxed{3} \text{ -}$	total power dissipation $T_{amb} = -40 \ ^{\circ}C \ to +125 \ ^{\circ}C$ SO16 package $[2] - 500$ TSSOP16 package $[3] - 500$

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

P<sub>tot</sub> derates linearly with 8 mW/K above 70 °C. [2]

 $P_{tot}$  derates linearly with 5.5 mW/K above 60  $^\circ\text{C}.$ [3]

P<sub>tot</sub> derates linearly with 4.5 mW/K above 60 °C. [4]

#### **Recommended operating conditions** 9.

#### **Recommended operating conditions** Table 4.

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC4	060-Q10	0	74HCT	Unit		
			Min	Тур	Max	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	$V_{CC}$	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	$V_{CC}$	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	-40	-	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

### 10. Static characteristics

#### Table 5. **Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	–40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC40	60-Q100									
V <sub>IH</sub>	HIGH-level	MR input								
	input voltage	$V_{CC} = 2.0 V$	1.5	1.3	-	1.5	-	1.5	-	V
		$V_{CC} = 4.5 V$	3.15	2.4	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0 V$	4.2	3.1	-	4.2	-	4.2	-	V
		RS input								
		$V_{CC} = 2.0 V$	1.7	-	-	1.7	-	1.7	-	V
		$V_{CC} = 4.5 V$	3.6	-	-	3.6	-	3.6	-	V
		$V_{CC} = 6.0 V$	4.8	-	-	4.8	-	4.8	-	V

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# 74HC4060-Q100; 74HCT4060-Q100

14-stage binary ripple counter with oscillator

Symbol	Parameter	Conditions		25 °C	;	–40 °C t	o +85 °C	–40 °C to	o +125 °C	Uni
			Min	Тур	Max	Min	Мах	Min	Max	-
/ <sub>IL</sub>	LOW-level	MR input								
	input voltage	$V_{CC} = 2.0 V$	-	0.8	0.5	-	0.5	-	0.5	V
		$V_{CC} = 4.5 V$	-	2.1	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	2.8	1.8	-	1.8	-	1.8	V
		RS input								
		$V_{CC} = 2.0 V$	-	-	0.3	-	0.3	-	0.3	V
		$V_{CC} = 4.5 V$	-	-	0.9	-	0.9	-	0.9	V
		$V_{CC} = 6.0 V$	-	-	1.2	-	1.2	-	1.2	V
он	HIGH-level	RTC output; RS = MR = GND								
	output	$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
	voltage	$I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O$ = -20 $\mu$ A; $V_{CC}$ = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O}$ = -2.6 mA; $V_{CC}$ = 4.5 V	3.98	-	-	3.84	-	3.7	-	V
		$I_{O} = -3.3 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	-	-	5.34	-	5.2	-	V
		RTC output; RS = MR = $V_{CC}$								
		$I_O$ = -20 $\mu$ A; $V_{CC}$ = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O$ = –20 $\mu\text{A};V_{CC}$ = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O$ = -20 $\mu$ A; $V_{CC}$ = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O}$ = -0.65 mA; $V_{CC}$ = 4.5 V	3.98	-	-	3.84	-	3.7	-	V
		$I_{O}$ = -0.85 mA; $V_{CC}$ = 6.0 V	5.48	-	-	5.34	-	5.2	-	V
		CTC output; RS = V <sub>IH</sub> ; MR = V <sub>IL</sub>								
		$I_O$ = -3.2 mA; $V_{CC}$ = 4.5 V	3.98	-	-	3.84	-	3.7	-	V
		$I_O$ = -4.2 mA; $V_{CC}$ = 6.0 V	5.48	-	-	5.34	-	5.2	-	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; except RTC output								
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	5.9	-	V
		$V_I = V_{IH} \text{ or } V_{IL};$ except RTC and CTC outputs								
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	-	-	3.84	-	3.7	-	V
		$I_0 = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	-	-	5.34	-	5.2	-	V

#### Table 5. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

# 74HC4060-Q100; 74HCT4060-Q100

14-stage binary ripple counter with oscillator

Symbol	Parameter	Conditions			25 °C		–40 °C t	o +85 °C	–40 °C to	o +125 ℃	Uni
				Min	Тур	Max	Min	Max	Min	Max	
/ <sub>OL</sub>	LOW-level output	RTC output; RS = V <sub>CC</sub> ; MR = GND							1		
	voltage	$I_0 = 20 \ \mu A; V_{CC} = 2.0 \ V$		-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 20 \ \mu A; V_{CC} = 4.5 \ V$		-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 6.0 \ V$		-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 2.6 \text{ mA}; V_{CC} = 4.5 \text{ V}$		-	-	0.26	-	0.33	-	0.4	V
		$I_0 = 3.3 \text{ mA}; V_{CC} = 6.0 \text{ V}$		-	-	0.26	-	0.33	-	0.4	V
		CTC output; RS = V <sub>IL</sub> ; MR = V <sub>IH</sub>									
		$I_0$ = 3.2 mA; $V_{CC}$ = 4.5 V		-	-	0.26	-	0.33	-	0.4	V
		$I_0 = 4.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$		-	-	0.26	-	0.33	-	0.4	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; except RTC output									
		$I_O = 20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$		-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$		-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 20 \ \mu A; V_{CC} = 6.0 \ V$		-	0	0.1	-	0.1	-	0.1	V
		$V_I = V_{IH} \text{ or } V_{IL};$ except RTC and CTC outputs									
		$I_0$ = 4.0 mA; $V_{CC}$ = 4.5 V		-	-	0.26	-	0.33	-	0.4	V
		$I_0 = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$		-	-	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0$ V		-	-	±0.1	-	±1.0	-	±1.0	μA
CC	supply current			-	-	8.0	-	80	-	160	μA
2	input capacitance			-	3.5	-	-	-	-	-	pF
4HCT4	060-Q100										
∕ін	HIGH-level input voltage	MR input; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	<u>[1]</u>	2.0	-	-	2.0	-	2.0	-	V
/ <sub>IL</sub>	LOW-level input voltage	MR input; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	<u>[1]</u>	-	-	0.8	-	0.8	-	0.8	V

#### Table 5. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

# 74HC4060-Q100; 74HCT4060-Q100

14-stage binary ripple counter with oscillator

Symbol	Parameter	Conditions		25 °C		-40 °C to	+85 °C	–40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V <sub>он</sub>	HIGH-level	RTC output; RS = MR = $V_{CC}$						1		
	output	$I_O = -20 \ \mu A; V_{CC} = 4.5 \ V$	4.4	4.5	-	4.4	-	4.4	-	V
	voltage	$I_{O}$ = -0.65 mA; $V_{CC}$ = 4.5 V	3.98	-	-	3.84	-	3.7	-	V
		RTC output; RS = MR = GND								
		$I_{O} = -20 \ \mu A; V_{CC} = 4.5 \ V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O}$ = -2.6 mA; $V_{CC}$ = 4.5 V	3.98	-	-	3.84	-	3.7	-	V
		CTC output; $RS = V_{IH}$ ; MR = $V_{IL}$								
		$I_{O}$ = -3.2 mA; $V_{CC}$ = 4.5 V	3.98	-	-	3.84	-	3.7	-	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; except RTC output								
		$I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	-	4.4	-	4.4	-	V
		$V_I = V_{IH}$ or $V_{IL}$ ; except RTC and CTC outputs								
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 4.5 V	3.98	-	-	3.84	-	3.7	-	V
0L	LOW-level output	RTC output; RS = V <sub>CC</sub> ; MR = GND								
	voltage	$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		$I_{O}$ = 2.6 mA; $V_{CC}$ = 4.5 V	-	-	0.26	-	0.33	-	0.4	V
		CTC output; $RS = V_{IL}$ ; MR = $V_{IH}$								
		$I_{O} = 3.2 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; except RTC output								
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		$V_I = V_{IH}$ or $V_{IL}$ ; except RTC and CTC outputs								
		$I_{O}$ = 4.0 mA; $V_{CC}$ = 4.5 V	-	-	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5$ V	-	-	±0.1	-	±1.0	-	±1.0	μΑ
СС	supply current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}; I_O = 0 \text{ A}$	-	-	8.0	-	80	-	160	μA
VI <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1$ V; other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5$ V to 5.5 V; $I_O = 0$ A	-	40	144	-	180	-	196	μA
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

#### Table 5. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

[1] For HCT4060-Q100, only input MR (pin 12) has TTL input switching levels.

14-stage binary ripple counter with oscillator

## **11. Dynamic characteristics**

#### Table 6. Dynamic characteristics

GND = 0 V;  $C_L = 50$  pF unless otherwise specified; for test circuit see <u>Figure 11</u>.

Symbol	Parameter	Conditions			25 °C		<b>−40</b> °C t	o +85 °C	–40 °C te	Unit	
				Min	Тур	Max	Min	Max	Min	Max	
74HC40	6 <b>0-</b> Q100										
t <sub>pd</sub>	propagation	RS to Q3; see Figure 8	[1]								
	delay	$V_{CC} = 2.0 V$		-	99	300	-	375	-	450	ns
		$V_{CC} = 4.5 V$		-	36	60	-	75	-	90	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	31	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$		-	29	51	-	64	-	77	ns
		Qn to Qn+1; see Figure 9	[2]								
		$V_{CC} = 2.0 V$		-	22	80	-	100	-	120	ns
		$V_{CC} = 4.5 V$		-	8	16	-	20	-	24	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	6	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$		-	6	14	-	17	-	20	ns
t <sub>PHL</sub>	HIGH to LOW	MR to Qn; see Figure 10									
	propagation	V <sub>CC</sub> = 2.0 V		-	55	175	-	220	-	265	ns
	delay	$V_{CC} = 4.5 V$		-	20	35	-	44	-	53	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF		-	17	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$		-	16	30	-	37	-	45	ns
t <sub>t</sub>	transition time	Qn; see Figure 8	[3]								
		$V_{CC} = 2.0 V$		-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5 V$		-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 V$		-	6	13	-	16	-	19	ns
t <sub>W</sub>	pulse width	RS (HIGH or LOW); see Figure 8									
		$V_{CC} = 2.0 V$		80	17	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V		16	6	-	20	-	24	-	ns
		$V_{CC} = 6.0 V$		14	5	-	17	-	20	-	ns
		MR (HIGH); see Figure 10									
		V <sub>CC</sub> = 2.0 V		80	25	-	100	-	120	-	ns
		$V_{CC} = 4.5 V$		16	9	-	20	-	24	-	ns
		$V_{CC} = 6.0 V$		14	7	-	17	-	20	-	ns
t <sub>rec</sub>	recovery time	MR to RS; see Figure 10									
	2	V <sub>CC</sub> = 2.0 V		100	28	-	125	-	150	-	ns
		$V_{CC} = 4.5 V$		20	10	-	25	-	30	-	ns
		$V_{CC} = 6.0 V$		17	8	-	21	-	26	-	ns
		00			-						

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14-stage binary ripple counter with oscillator

Symbol	Parameter	Conditions			25 °C		–40 °C t	o +85 °C	–40 °C to	o +125 ℃	Unit
				Min	Тур	Max	Min	Мах	Min	Мах	
f <sub>max</sub>	maximum	RS; see <u>Figure 8</u>									
	frequency	$V_{CC} = 2.0 V$		6	26	-	4.8	-	4	-	MHz
		$V_{CC} = 4.5 V$		30	80	-	24	-	20	-	MHz
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	87	-	-	-	-	-	MHz
		$V_{CC} = 6.0 V$		35	95	-	28	-	24	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$V_{I}$ = GND to $V_{CC}$ ; $V_{CC}$ = 5 V; $f_{i}$ = 1 MHz	<u>[4]</u>	-	40	-	-	-	-	-	pF
74HCT4	060-Q100										
t <sub>pd</sub>	propagation	RS to Q3; see Figure 8	[1]								
	delay	$V_{CC} = 4.5 V$		-	33	66	-	83	-	99	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	31	-	-	-	-	-	ns
		Qn to Qn+1; see Figure 9	[2]								
		$V_{CC} = 4.5 V$		-	8	16	-	20	-	24	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	6	-	-	-	-	-	ns
t <sub>PHL</sub>	HIGH to LOW	MR to Qn; see Figure 10									
	propagation delay	$V_{CC}$ = 4.5 V		-	21	44	-	55	-	66	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	18	-	-	-	-	-	ns
t <sub>t</sub>	transition time	Qn; see Figure 8	[3]								
		$V_{CC} = 4.5 V$		-	7	15	-	19	-	22	ns
t <sub>W</sub>	pulse width	RS (HIGH or LOW); see <u>Figure 8</u>									
		$V_{CC} = 4.5 V$		16	6	-	20	-	24	-	ns
		MR (HIGH); see Figure 10									
		$V_{CC} = 4.5 V$		16	6	-	20	-	24	-	ns
rec	recovery time	MR to RS; see Figure 10									
		$V_{CC} = 4.5 V$		26	13	-	33	-	39	-	ns
max	maximum	RS; see Figure 8									
	frequency	$V_{CC} = 4.5 V$		30	80	-	24	-	20	-	MHz
		$V_{CC}$ = 5.0 V; C <sub>L</sub> = 15 pF		-	88	-	-	-	-	-	MHz

#### Dynamic characteristics ... continued Table 6.

t airauit and Fir . . .

#### 14-stage binary ripple counter with oscillator

Symbol	Parameter	Conditions			25 °C			–40 °C to +85 °C		o +125 ℃	Unit
				Min	Тур	Max	Min	Max	Min	Max	
C <sub>PD</sub>	power dissipation capacitance	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ to } V_{CC} - 1.5 \text{ V}; \\ V_{CC} = 5 \text{ V};  f_{i} = 1 \text{ MHz} \end{array}$	<u>[4]</u>	-	40	-	-	-	-	-	pF
[1] t <sub>pd</sub> is t	the same as t <sub>PHL</sub>	and t <sub>PLH</sub> .									
[2] Qn+1	is the next Qn o	utput.									
[3] t <sub>t</sub> is th	ie same as t <sub>THL</sub> a	and t <sub>TLH</sub> .									
(41 C id	s used to determi	ine the dynamic power dissination	(D_	in							

#### Table 6. Dynamic characteristics ... continued

 $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ): [4]

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

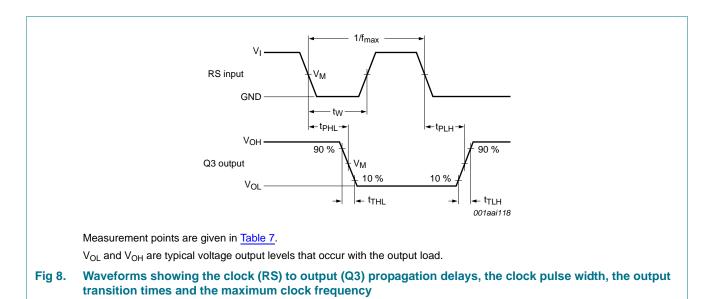
 $f_o = output frequency in MHz;$ 

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

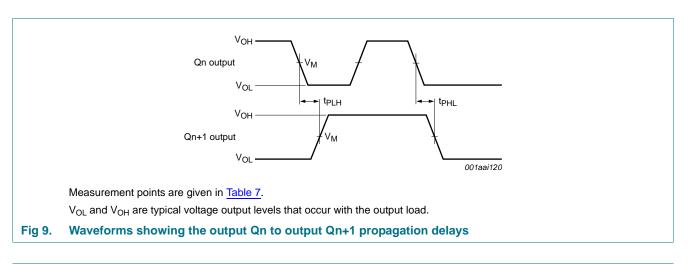
N = number of inputs switching;  $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

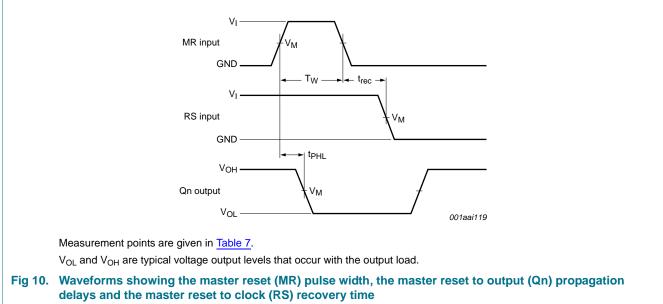
### 12. Waveforms



# 74HC4060-Q100; 74HCT4060-Q100

14-stage binary ripple counter with oscillator





#### Table 7. Measurement points

Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74HC4060-Q100	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
74HCT4060-Q100	1.3 V	1.3 V

14-stage binary ripple counter with oscillator

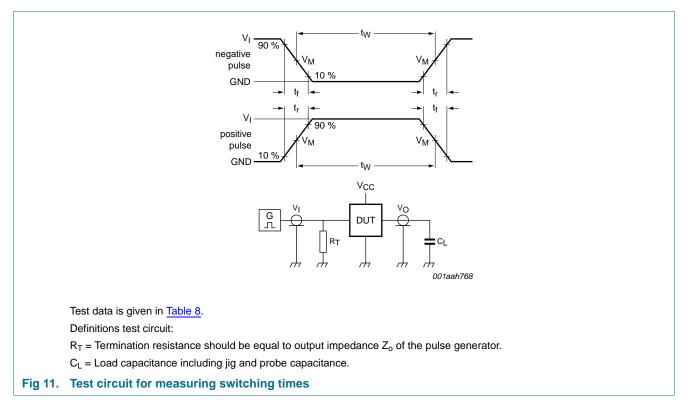


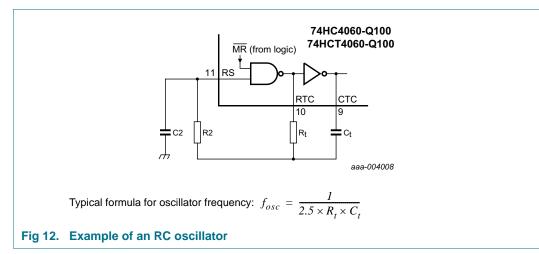
Table 8. Test data			
Туре	Input		Load
	VI	t <sub>r</sub> , t <sub>f</sub>	CL
74HC4060-Q100	V <sub>CC</sub>	6 ns	15 pF, 50 pF
74HCT4060-Q100	3 V	6 ns	15 pF, 50 pF

14-stage binary ripple counter with oscillator

### 13. RC oscillator

#### **13.1 Timing component limitations**

The oscillator frequency is mainly determined by  $R_tC_t$ , provided  $R2 \approx 2R_t$  and  $R2C2 << R_tC_t$ . The function of R2 is to minimize the influence of the forward voltage across the input protection diodes on the frequency. The stray capacitance C2 should be kept as small as possible. In consideration of accuracy,  $C_t$  must be larger than the inherent stray capacitance.  $R_t$  must be larger than the ON resistance in series with it, which typically is 280  $\Omega$  at  $V_{CC} = 2.0$  V, 130  $\Omega$  at  $V_{CC} = 4.5$  V and 100  $\Omega$  at  $V_{CC} = 6.0$  V.



The recommended values for these components to maintain agreement with the typical oscillation formula are:

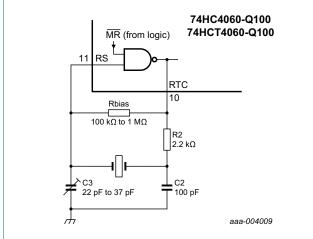
 $C_t$  > 50 pF, up to any practical value and 10 k $\Omega$  <  $R_t$  < 1 M $\Omega$ .

In order to avoid start-up problems,  $R_t \ge 1 \ k\Omega$ .

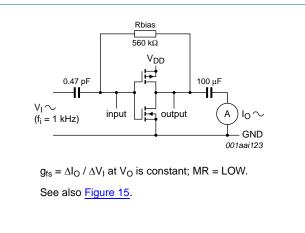
#### 13.2 Typical crystal oscillator circuit

In Figure 13, R2 is the power limiting resistor. For starting and maintaining oscillation, a minimum transconductance is necessary, so R2 must not be too large. A practical value for R2 is 2.2 k $\Omega$ .

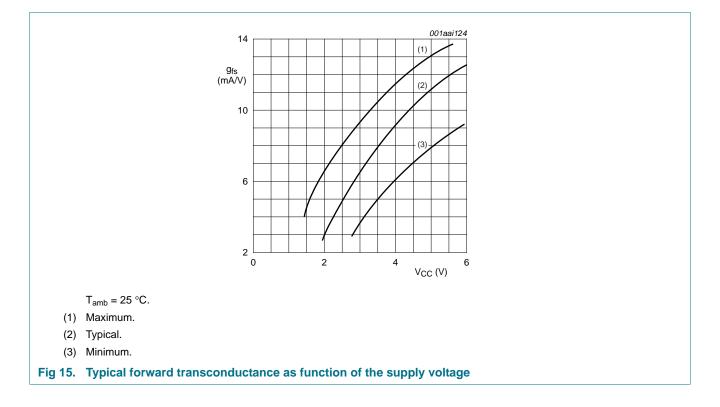
14-stage binary ripple counter with oscillator





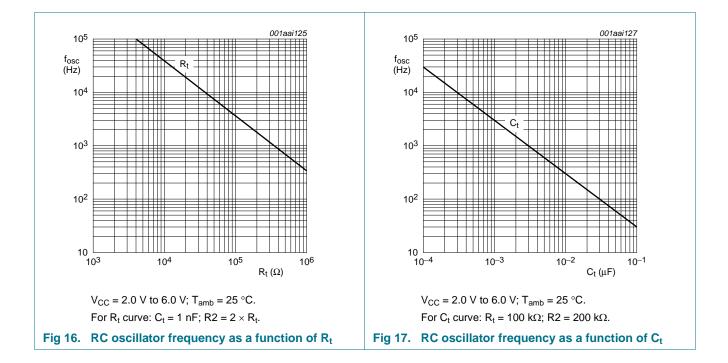






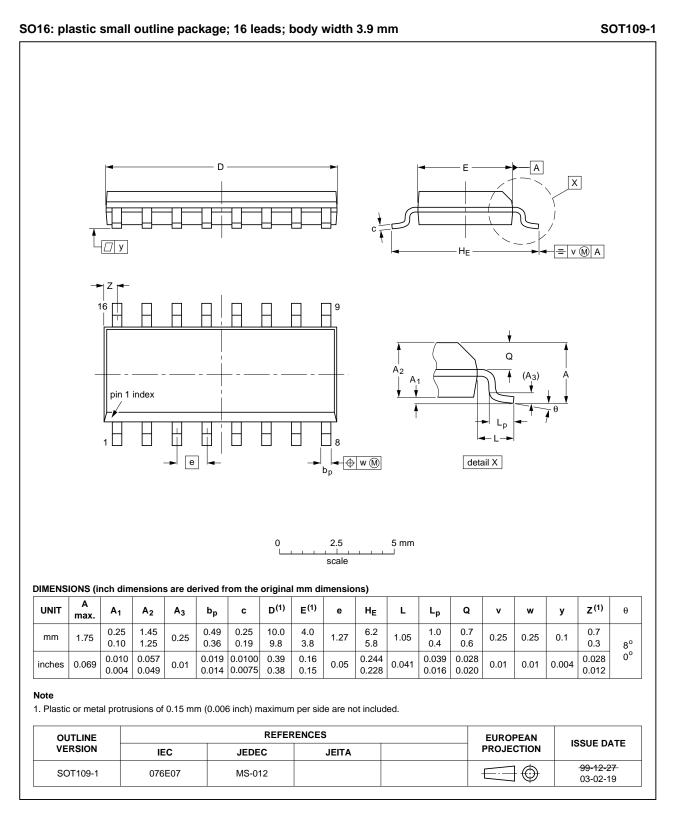
# 74HC4060-Q100; 74HCT4060-Q100

14-stage binary ripple counter with oscillator



14-stage binary ripple counter with oscillator

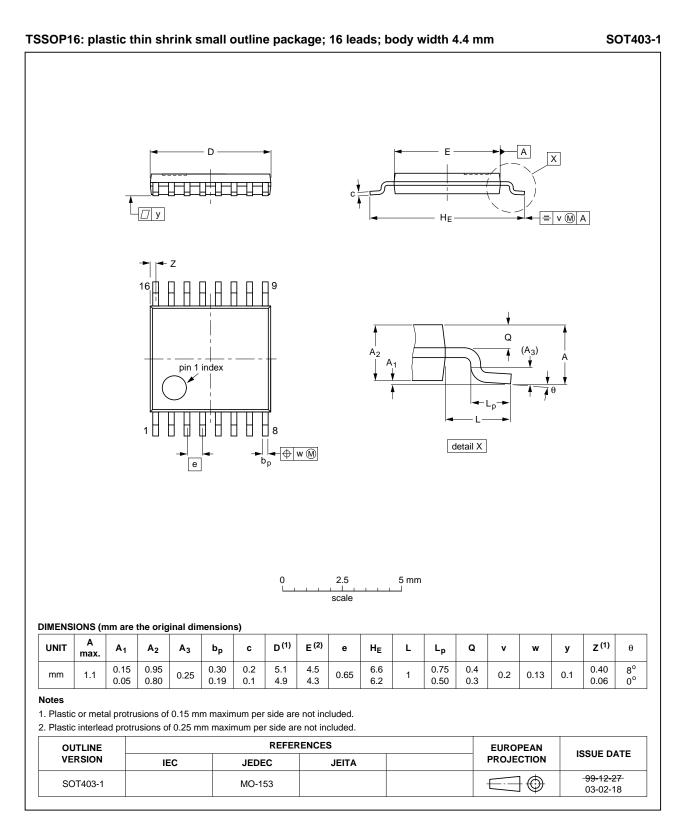
## 14. Package outline



#### Fig 18. Package outline SOT109-1 (SO16)

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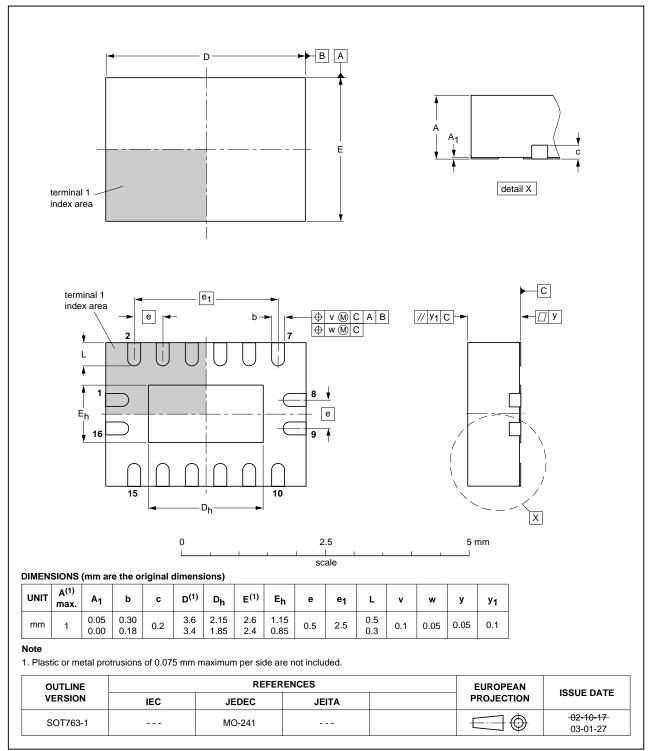
14-stage binary ripple counter with oscillator



#### Fig 19. Package outline SOT403-1 (TSSOP16)

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14-stage binary ripple counter with oscillator



DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

#### Fig 20. Package outline SOT763-1 (DHVQFN16)

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14-stage binary ripple counter with oscillator

## **15. Abbreviations**

Table 9.	Abbreviations	
Acronym	Description	
CMOS	Complementary Metal-Oxide Semiconductor	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
HBM	Human Body Model	
MM	Machine Model	
TTL	Transistor-Transistor Logic	
MIL	Military	

## **16. Revision history**

Table 10. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4060_Q100 v.1	20120802	Product data sheet	-	-

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## 17. Legal information

### **17.1 Data sheet status**

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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